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Middle Power LED Series 3030

LM302A CRI 70



LM302A leads lighting design trend with high performance and efficacy

Features & Benefits

- 1 W class middle-high power LED
- EMC resin for high reliability
- Standard form factor for design flexibility
- High performance and efficacy





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1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Operating Temperature	Ta	-40 ~ +85	°C	-
Storage Temperature	T _{stg}	-40 ~ +100	°C	-
LED Junction Temperature	Tj	125	°C	-
Forward Current	IF	200	mA	-
Peak Pulsed Forward Current	I _{Fp}	400	mA	Duty 1/10, pulse width 10 ms
Assembly Process Temperature	-	260 <10	°C s	-
ESD (HBM)	_	5	kV	-



b) Electro-optical Characteristics ($I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$)

ltem	Nominal CCT (K)	Rank	Bin	Min.	Тур.	Max.	Unit
			BZ	5.8	-	6.0	
			B1	6.0	-	6.2	
Forward Voltage (VF)		GB	B2	6.2	-	6.4	V
			B3	6.4	-	6.6	
			B4	6.6	-	6.8	
	3000	SO	S3	112	-	120	
	3000	50	S4	120	-	128	
	4000	S0	S3	117	-	125	
	4000		S4	125	-	133	
Luminous Flux (Ф _v)	5000	0.0	S3	121	-	129	lm
	5000	SO	S4	129	-	137	
		0.0	S3	119	-	127	
	5700	SO	S4	127	-	135	
Reverse Voltage (@ 5 mA)				0.7	-	1.2	V
Color Rendering Index (Ra)		3		70	-	-	-
Thermal Resistance (junction to solder point)				-	12	-	°C/W
Beam Angle				-	120	-	0

Note:

Samsung maintains measurement tolerance of: forward voltage = ± 0.1 V, luminous flux = ± 5 %, CRI = ± 3



2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
	Р																

Digit	PKG Information	Code	Specification
1 2 3	Samsung Package Middle Power	SPM	
4 5	Color	WH	White
6	Product Version	т	
789	Form Factor	327	3.0 x 3.0 x 0.65 mm; 2 pads; LM302
10	Sorting Current	F	150 mA
11	Chromaticity Coordinates	D	ANSI Standard
12	CRI	3	Min. 70 25°C
13 14	Forward Voltage (V)	G B	BZ 5.8~6.0 B1 6.0~6.2 5.8~6.8 Bin Code: B2 6.2~6.4 B3 6.4~6.6 B4 6.6~6.8
15 16	CCT (K)	V☆ T☆ R☆ Q☆	3000 V1, V2, V3, V4, V5, V6, V7, V8, V9, VA, VB, VC, VD, VE, VF, VG 4000 T1, T2, T3, T4, T5, T6, T7, T8, T9, TA, TB, TC, TD, TE, TF, TG 5000 R1, R2, R3, R4, R5, R6, R7, R8, R9, RA 5700 Q1, Q2, Q3, Q4, Q5, Q6, Q7, Q8, Q9, QA ★: "0" (Whole bin) or "M" (Quarter bin)
17 18	Luminous Flux (Im)	S 0	Bin Code: S3, S4



a) Luminous Flux Bins ($I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$)

CRI Min.	Product Code	Flux Bin	Flux Range (Φ _v , Im)
		<u>60</u>	112 ~ 120
70	3PMW01327FD3GDV × 30	50	120 ~ 128
70	SPMWHT327FD3GBV☆S3	S3	112 ~ 120
	SPMWHT327FD3GBV☆S4	S4	120 ~ 128
		80	117 ~ 125
70	3FMW113271 D30B1 A 30	30	125 ~ 133
70	SPMWHT327FD3GBT☆S3	S3	117 ~ 125
	SPMWHT327FD3GBT☆S4	S4	125 ~ 133
		80	121 ~ 129
70	SEMIWITISZA DOGBAROU	30	129 ~ 137
70	SPMWHT327FD3GBR☆S3	S3	121 ~ 129
	SPMWHT327FD3GBR☆S4	S4	129 ~ 137
		S3	119 ~ 127
70		S4	127 ~ 135
70	SPMWHT327FD3GBQ☆S3	S3	119 ~ 127
	SPMWHT327FD3GBQ☆S4	S4	127 ~ 135
		Min.Product Code70SPMWHT327FD3GBV\$\$070SPMWHT327FD3GBV\$\$370SPMWHT327FD3GBV\$\$470SPMWHT327FD3GBT\$\$070SPMWHT327FD3GBT\$\$370SPMWHT327FD3GBT\$\$370SPMWHT327FD3GBT\$\$370SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$070SPMWHT327FD3GBR\$\$0	Min. Product Code Flux Bin 3 SPMWHT327FD3GBV \$\$ \$\$ \$\$ 70 SPMWHT327FD3GBT \$\$ \$\$ \$\$ 70 SPMWHT327FD3GBR \$\$ \$\$ \$\$ 70 SPMWHT327FD3GBQ \$\$ \$\$ \$\$ 70 SPMWHT327FD3GBQ \$\$ \$\$ \$\$ 70 SPMWHT327FD3GBQ \$\$ \$\$ \$\$

Note:



b) Color Bins (IF = 150 mA, Ts = 25 °C)

Nominal CCT CRI (K) Min.		Product Code	Color Rank	Chromaticity Bins
		SPMWHT327FD3GBV0S★	V0	V1, V2, V3, V4, V5, V6, V7, V8,
3000	70		(Whole bin)	V9, VA, VB, VC, VD, VE, VF, VG
		SPMWHT327FD3GBVMS★	VM (Quarter bin)	V6, V7, VA, VB
		SPMWHT327FD3GBT0S★	TO	T1, T2, T3, T4, T5, T6, T7, T8,
4000	70		(Whole bin)	T9, TA, TB, TC, TD, TE, TF, TG
1000	10	SPMWHT327FD3GBTMS★	ТМ	T6, T7, TA, TB
		SPMWH132/FD3GB1MS×	(Quarter bin)	10, 11, 10, 12
			R0	R1, R2, R3, R4, R5
5000	70	SPMWHT327FD3GBR0S★	(Whole bin)	R6, R7, R8, R9, RA
5000	70		RM	R1, R2, R3, R4, R5, R6
		SPMWHT327FD3GBRMS★	(Quarter bin)	11, 112, 110, 114, 110, 110
			Q0	Q1, Q2, Q3, Q4, Q5
		SPMWHT327FD5GBQ0S★	(Whole bin)	Q6, Q7, Q8, Q9, QA
5700	70		QM	Q1, Q2, Q3, Q4, Q5, Q6
		SPMWHT327FD5GBQMS★	(Quarter bin)	UI, UZ, US, U4, U5, UD

Note:

" \star " can be "0", "3" or "4" of the luminous flux binning

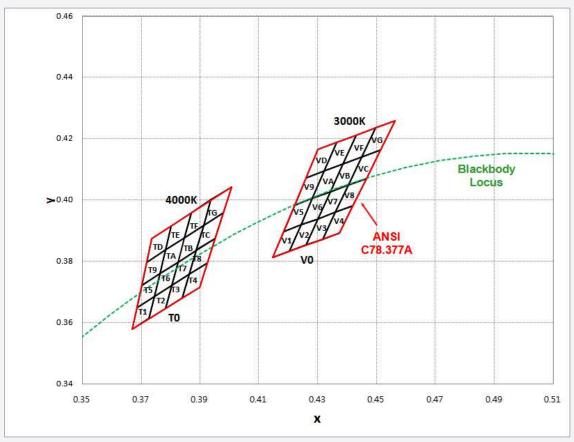


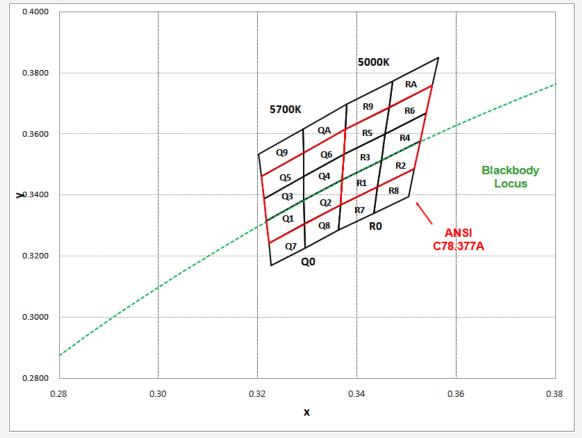
c) Voltage Bins (I_F = 150 mA, T_s = 25 °C)

Nominal CCT (K)	CRI Min.	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
				BZ	5.8 ~ 6.0
			B1	6.0 ~ 6.2	
-		GB	B2	6.2 ~ 6.4	
				B3	6.4 ~ 6.6
				B4	6.6 ~ 6.8











d) Chromaticity Region & Coordinates (IF = 150 mA, Ts = 25 °C)

Region	CIEx	CIE y	Region	CIE x	CIE y
		V rank	(3000 K)		
5	0.4147	0.3814		0.4221	0.3984
1/4	0.4183	0.3898	10	0.4259	0.4073
V1	0.4242	0.3919	V9	0.4322	0.4096
	0.4203	0.3833	*	0.4281	0.4006
	0.4203	0.3833		0.4281	0.4006
10	0.4242	0.3919		0.4322	0.4096
V2	0.4300	0.3939	VA	0.4385	0.4119
	0.4259	0.3853	•	0.4342	0.4028
	0.4259	0.3853		0.4342	0.4028
	0.4300	0.3939		0.4385	0.4119
V3	0.4359	0.3960	VB	0.4449	0.4141
	0.4316	0.3873	•	0.4403	0.4049
	0.4316	0.3873		0.4403	0.4049
	0.4359	0.3960		0.4449	0.4141
V4	0.4418 0.398	0.3981	VC	0.4513	0.4164
	0.4373	0.3893		0.4465	0.4071
	0.4183	0.3898		0.4259	0.4073
	0.4221	0.3984		0.4299	0.4165
V5	0.4281	0.4006	VD	0.4364	0.4188
	0.4242	0.3919		0.4322	0.4096
	0.4242	0.3919		0.4322	0.4096
	0.4281	0.4006		0.4364	0.4188
V6	0.4342	0.4028	VE	0.4430	0.4212
	0.4300	0.3939		0.4385	0.4119
	0.4300	0.3939		0.4385	0.4119
	0.4342	0.4028		0.4430	0.4212
V7	0.4403	0.4049	VF	0.4496	0.4236
	0.4359	0.3960		0.4449	0.4141
	0.4359	0.3960		0.4449	0.4141
1.10	0.4403	0.4049	1/2	0.4496	0.4236
V8	0.4465	0.4071	VG	0.4562	0.4260
	0.4418	0.3981		0.4513	0.4164

Region	Region CIE x		Region	CIEx	CIE y
		T rank	(4000 K)		
	0.3670	0.3578		0.3702	0.3722
74	0.3726	0.3612		0.3763	0.3760
T1	0.3744	0.3685	Т9	0.3782	0.3837
	0.3686	0.3649		0.3719	0.3797
	0.3726	0.3612		0.3763	0.3760
To	0.3783	0.3646		0.3825	0.3798
T2	0.3804	0.3721	TA	0.3847	0.3877
	0.3744	0.3685		0.3782	0.3837
	0.3783	0.3646		0.3825	0.3798
	0.3840	0.3681		0.3887	0.3836
Т3	0.3863	0.3758	ТВ	0.3912	0.3917
	0.3804	0.3721		0.3847	0.3877
	0.3840	0.3681		0.3887	0.3837
	0.3898	0.3716		0.3950	0.3875
Τ4	0.3924	0.3794	тс	0.3978	0.3958
	0.3863	0.3758		0.3912	0.3917
	0.3686	0.3649		0.3719	0.3797
	0.3744	0.3685		0.3782	0.3837
Τ5	0.3763	0.3760	TD	0.3802	0.3916
	0.3702	0.3722		0.3736	0.3874
	0.3744	0.3685		0.3782	0.3837
	0.3804	0.3721		0.3847	0.3877
Τ6	0.3825	0.3798	TE	0.3869	0.3958
	0.3763	0.376		0.3802	0.3916
	0.3804	0.3721		0.3847	0.3877
	0.3863	0.3758		0.3912	0.3917
Τ7	0.3887	0.3836	TF	0.3937	0.4001
	0.3825	0.3798		0.3869	0.3958
	0.3863	0.3758		0.3912	0.3917
	0.3924	0.3794		0.3978	0.3958
Т8	0.3950	0.3875	TG	0.4006	0.4044
	0.3887	0.3836		0.3937	0.4001



d) Chromaticity Region & Coordinates

Region	CIE x	CIE y	Region	CIE x	CIE y		Region	CIEx	CIE y	Region	CIE x	CIE y
	•	R rank	(5000 K)						Q rank	(5700 K)		
	0.3366	0.3369	50	0.3456	0.3601			0.3222	0.3243		0.3292	0.3461
	0.3441	0.3428		0.3539	0.3669		01	0.3294	0.3306		0.3373	0.3534
R1	0.3449	0.3515	R6	0.3551	0.3760		Q1	0.3293	0.3384	Q6	0.3376	0.3616
	0.3369	0.3451		0.3464	0.3688			0.3217	0.3316		0.3292	0.3539
	0.3441	0.3428		0.3363	0.3287			0.3294	0.3306		0.3227	0.3170
DO	0.3515	0.3487		0.3433	0.3341			0.3366	0.3369	Q7	0.3295	0.3228
R2	0.3527	0.3578		0.3441	0.3428		Q2	0.3369	0.3451		0.3294	0.3306
	0.3449	0.3515		0.3366	0.3369			0.3293	0.3384		0.3222	0.3243
	0.3369	0.3451	R8	0.3433	0.3341			0.3217	0.3316		0.3295	0.3228
DO	0.3449	0.3515		0.3503	0.3396		Q3	0.3293	0.3384	Q8	0.3363	0.3287
R3	0.3456	0.3601		0.3515	0.3487			0.3292	0.3461		0.3366	0.3369
	0.3373	0.3534		0.3441	0.3428			0.3212	0.3389		0.3294	0.3306
	0.3449	0.3515		0.3376	0.3616			0.3293	0.3384		0.3207	0.3462
D4	0.3527	0.3578	DO	0.3464	0.3688		01	0.3369	0.3451	Q9	0.3292	0.3539
R4	0.3539	0.3669	R9	0.3471	0.3775		Q4	0.3373	0.3534	Q9	0.3291	0.3617
	0.3456	0.3601		0.3379	0.3698			0.3292	0.3461		0.3202	0.3535
	0.3373	0.3534		0.3464	0.3688			0.3212	0.3389		0.3292	0.3539
DE	0.3456	0.3601		0.3551	0.3760	Q5	05	0.3292	0.3461	QA	0.3376	0.3616
R5	0.3464	0.3688	RA	0.3564	0.3851		Qo	0.3292	0.3539	QA	0.3379	0.3698
	0.3376	0.3616		0.3471	0.3775			0.3207	0.3462		0.3291	0.3617

Note:

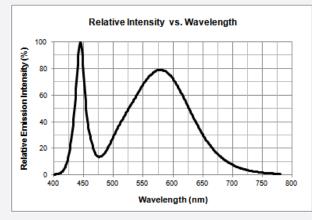
Samsung maintains measurement tolerance of: Cx, Cy = ± 0.005



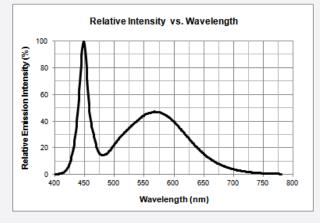
3. Typical Characteristics Graphs

a) Spectrum Distribution ($I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$)

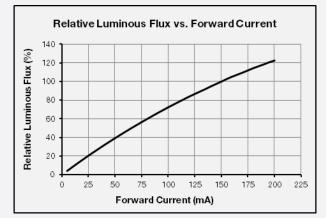
сст: 3000 к



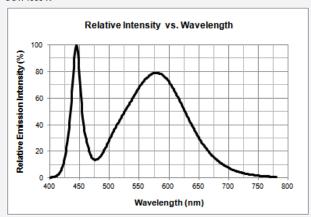
ССТ:5000 К



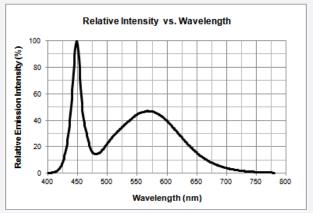
b) Forward Current Characteristics (T_s = 25 °C)

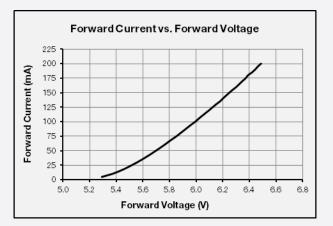


ССТ: 4000 К



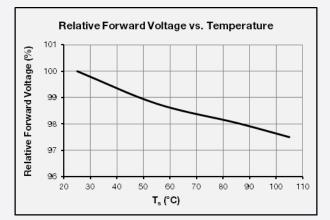
CCT: 5700 K



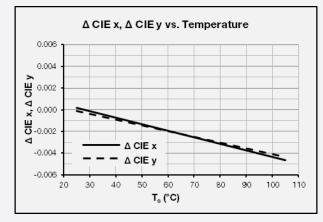


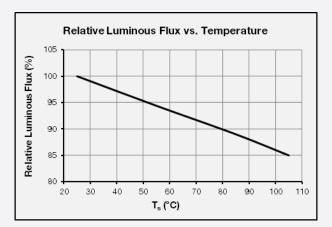


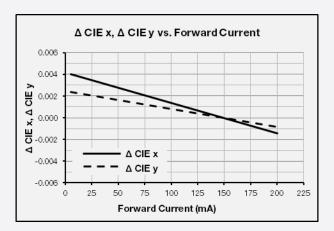
c) Temperature Characteristics ($I_F = 150 \text{ mA}$)



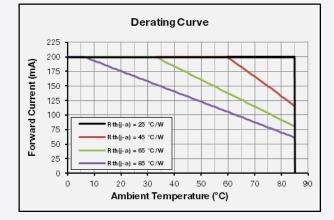
d) Color Shift Characteristics (T_s = 25 °C, I_F = 150 mA)

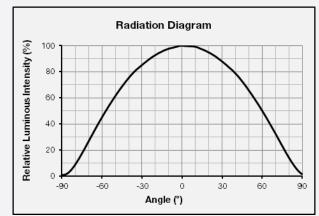


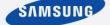




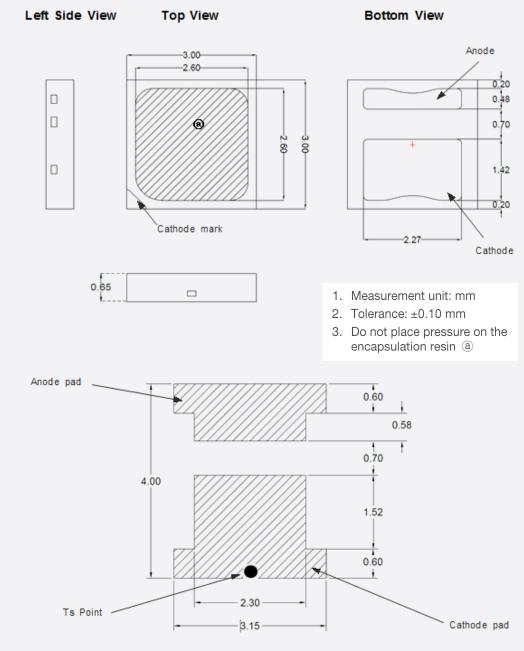
e) Derating Curve and Beam Angle Characteristics ($I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$)







4. Outline Drawing & Dimension



Recommended Land Pattern

Notes:

- 1) This LED has built-in ESD protection device(s) connected in parallel to LED chip(s).
- 2) T_s point and measurement method:
 - 1 Measure one point at the cathode pad. If necessary, remove PSR of PCB to reach T_s point.
 - ② All pads must be soldered to the PCB to dissipate heat properly, otherwise the LED can be damaged.

14



Precautions:

- Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
- 2) Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair.
- Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.



5. Reliability Test Items and Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle	Sample Size
Room Temperature Life Test	25 °C, DC 200 mA	1000 h	22
High Temperature Life Test	85 °C, DC 200 mA	1000 h	22
High Temperature Humidity Life Test	85 °C, 85 % RH, DC 200 mA	1000 h	22
Low Temperature Life Test	-40 °C, DC 200 mA	1000 h	22
Powered Temperature Cycle Test	-45 °C / 20 min \leftrightarrow 85 °C / 20 min, sweep 100 min cycle on/off: each 5 min, DC 200 mA	100 cycles	22
Thermal Cycle	-45 °C / 15 min ↔ 125 °C / 15 min → Hot plate 180 °C	500 cycles	100
High Temperature Storage	120 °C	1000 h	11
Low Temperature Storage	-40 °C	1000 h	11
ESD (HBM)	R ₁ : 10 MΩ R ₂ : 1.5 KΩ C: 100 pF V: ±5 KV	5 times	30
ESD (MM)	R _i : 10 MΩ R ₂ : 0 C: 200 pF V: ±0.5 kV	5 times	30
Vibration Test	20~2000~20 Hz, 200 m/s², sweep 4 min X, Y, Z 3 direction, each 1 cycle	4 cycles	11
Mechanical Shock Test	1500 g, 0.5 ms 3 shocks each X-Y-Z axis	5 cycles	11

b) Criteria for Judging the Damage

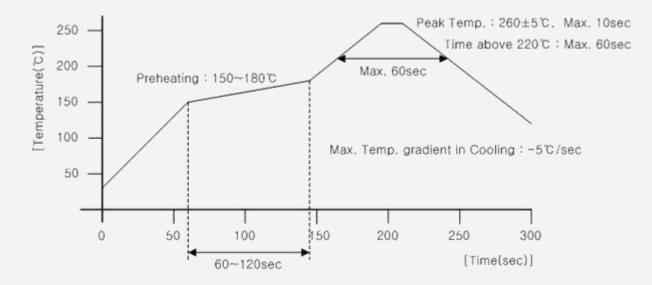
	ltem	Symbol	Test Condition (T _s = 25 °C)	Limit		
				Min.	Max.	
	Forward Voltage	VF	I _F = 150 mA	Init. Value * 0.9	Init. Value * 1.1	
	Luminous Flux	Φ _v	I _F = 150 mA	Init. Value * 0.7	Init. Value * 1.1	



6. Soldering Conditions

a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.



b) Manual Soldering Conditions

Not more than 5 seconds @ max. 300 °C, under soldering iron.

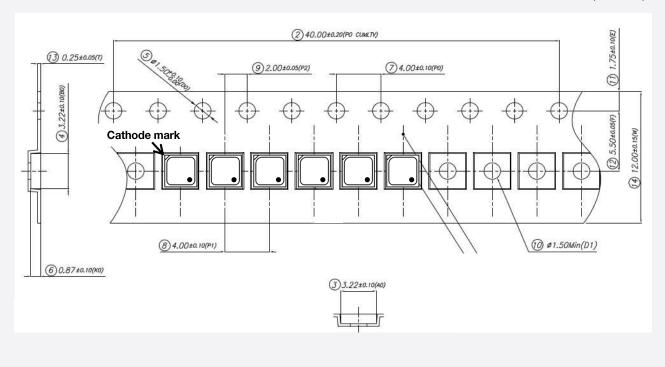


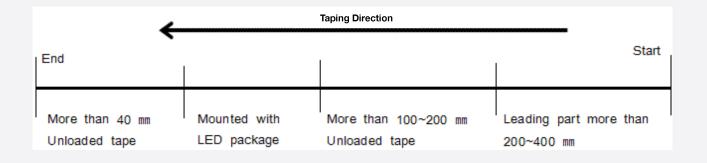


7. Tape & Reel

a) Taping Dimension

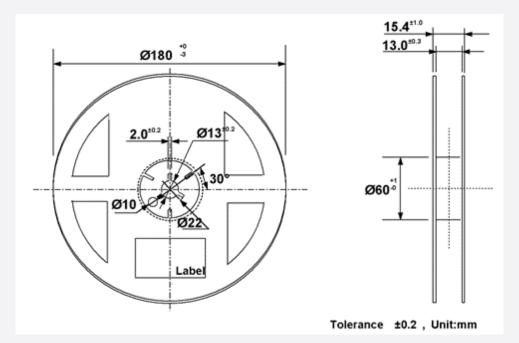
(unit: mm)







b) Reel Dimension



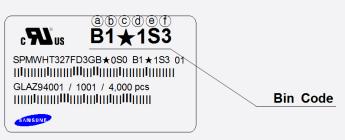
Notes:

- 1) Quantity: The quantity/reel is 4,000 pcs
- 2) Cumulative tolerance: Cumulative tolerance / 10 pitches is ±0.2 mm
- 3) Adhesion strength of cover tape: Adhesion strength is 0.1-0.7 N when the cover tape is turned off from the carrier tape at 10° angle to the carrier tape
- 4) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag



8. Label Structure

a) Label Structure



Note: Denoted bin code and product code above is only an example '★' means all kind of Chromaticity Coordinate Ranks

Bin Code:

- (a)(b): Forward Voltage bin (refer to page 7)
- ©: Chromaticity bin (refer to page 9~12)
- (e)(f): Luminous Flux bin (refer to page 4-5)

b) Lot Number

The lot number is composed of the following characters:



123456789/1abc /4,000 pcs

1	: Production site (S: Giheung, Korea, G: Tianjin, China)	
2	: L (LED)	
3	: Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)	
4	: Year (Z: 2015, A: 2016, B: 2017)	
5	: Month (1~9, A, B, C)	
6	: Day (1~9, A, B~V)	
789	: Product serial number (001 ~ 999)	
abc	: Reel number (001 ~ 999)	

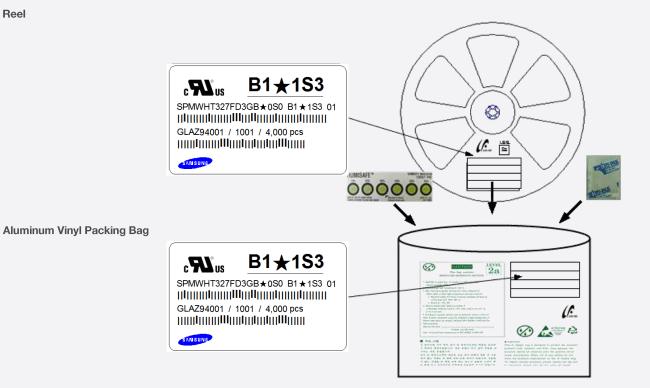




9. Packing Structure

a) Packing Process

Reel

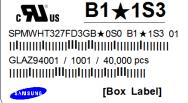


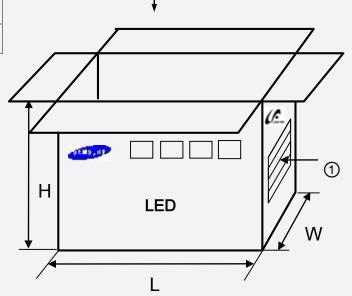
Outer Box

Material: Paper (SW3B(B))

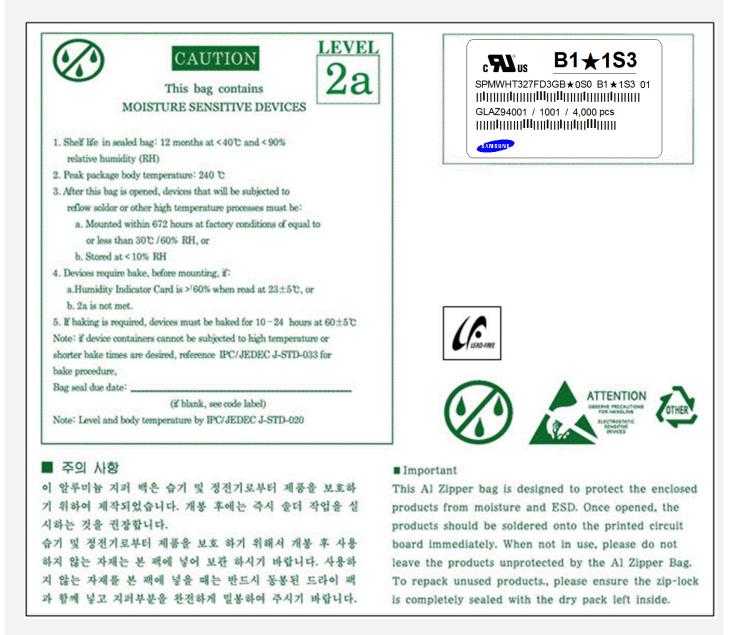
Тиро		Note		
Туре	L	W	Н	Note
7 inch L	245 ± 5	220 ± 5	182 ± 5	Up to 10 reels
7 inch S	245 ± 5	220 ± 5	86 ± 5	Up to 5 reels











c) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag







10. Precautions in Handling & Use

- 1) For over-current-proof function, customers are recommended to apply resistors to prevent sudden change of the current caused by slight shift of the voltage.
- This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When washing is required, IPA is recommended to use.
- 3) When the LEDs illuminate, operating current should be decided after considering the ambient maximum temperature.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed by a sealed container with nitrogen gas injected (shelf life of sealed bags: 12 months, temperature ~40 °C, ~90 % RH).
- After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 b. Stored at <10 % RH
- 6) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 8) Devices must be baked for $10 \sim 24$ hours at 60 ± 5 °C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leak current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires (fixtures). In order to prevent these problems, we recommend users to know the physical properties of the materials used in luminaires, and they must be selected carefully.
- 11) Risk of sulfurization (or tarnishing)

The LED from Samsung Electronics Co., Ltd. uses a silver-plated lead frame and its surface color may change to black (or dark colored) when it is exposed to sulfur (S), chlorine (CI) or other halogen compound. Sulfurization of lead frame may cause intensity degradation, change of chromaticity coordinates and, in extreme cases, open circuit. It requires caution. Due to possible sulfurization of lead frame, LED should not be used and stored together with oxidizing substances made of materials such as: rubber, plain paper, lead solder cream, etc.



Legal and additional information.

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